agnetic transition in CeRu₂Si₂ etc. CeAg₂Ge₂ also crystallizes in the tetragonal ThCr₂Si₂ type crystal structure. Previous reports of CeAg₂Ge₂ were on polycrystalline samples and there were conflicting reports on the antiferromagnetic ordering temperature [1,2,3]. Furthermore, the ground state properties of CeAg₂Ge₂ are also quite intriguing. Neutron scattering experiments on a polycrystalline sample could detect only one excited state at 11 meV indicating that the ground state and the first excited states are closely spaced. In order to study the anisotropic physical properties and to study the crystalline electric field ground state, we have grown the single crystals of CeAg₂Ge₂.

Single crystals of CeAg₂Ge₂ were grown by self flux method, using Ag:Ge (75.5: 24.5) binary alloy, which forms an eutectic at 650 °C, as flux. The details about the crystal

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reduction in the spin-disorder scattering caused by the antiferromagnetic ordering of the magnetic moments, as seen in the inset of Fig. 1(a). The antiferromagnetic transition can be clearly seen at 4.6 K as indicated by the arrow in the figure.

Figure 1(b) shows the temperature dependence of the magnetic susceptibility along the two principle directions. As can be seen from the figure there is a large anisotropy in the susceptibility due to tetragonal crystal structure. The high temperature susceptibility does not obey the simple Curie-Weiss law; on the other hand it can be very well fitted to a modified Curie-Weiss law which is given by $\chi =$ $\chi_0 + \frac{C}{T - \theta_0}$, where χ_0 is the temperature independent part of the magnetic susceptibility and C is the Curie constant. The value of χ_0 was estimated to be 1.33×10^{-3} and 1.41×10^{-3} emu/mol for $H \parallel [001]$ and [100], respectively such that an effective moment of 2.54 $\mu_{\rm B}/{\rm Ce}$ is obtained for

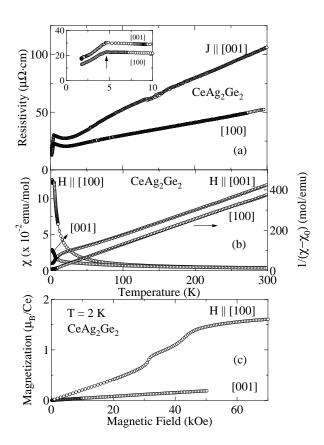


Fig. 1. (a) The temperature dependence of electrical resistivity of $CeAg_2Ge_2$, inset shows the low temperature part, (b) Temperature dependence of the magnetic susceptibility together with inverse magnetic susceptibility plot, solid lines indicate the CEF fitting and (c) Magnetization of $CeAg_2Ge_2$ measured at T=2 K.

temperatures above 100 K. In order to perform the CEF analysis of the susceptibility data, we plotted the inverse susceptibility as $1/(\chi - \chi_0)$ versus T. The solid line in figure 1(b) are the fitting to the inverse susceptibility with the CEF Hamiltonian given by $\mathcal{H}_{CEF} = B_2^0 O_2^0 + B_4^0 O_4^0 + B_4^4 O_4^4$, where B_l^m and O_l^m are CEF parameters and the Stevens operators respectively. The level splitting energies are estimated to be $\Delta_1 = 5$ K and $\Delta_2 = 130$ K. It may be noted that the first excited state is very close to the ground state indicating that the ground state is a quasi-quartet state. Figure 1(c) shows the field dependence of magnetization at 2 K. For $H \parallel [100]$, the magnetization increases linearly with the field and exhibit two metamagnetic transition at $H_{\rm m1}=31$ kOe and $H_{\rm m2}=44.7$ kOe before it saturates at $1.6 \mu_{\rm B}/{\rm Ce}$ at 70 kOe, indicating the easy axis of magnetization. On the other hand the magnetization along [001] is very small and varies linearly with field reaching a value of $0.32 \mu_{\rm B}/{\rm Ce}$ at 50 kOe.

Figure 2(a) shows the temperature dependence of the specific heat of CeAg_2Ge_2 together with the specific heat of a reference sample LaAg_2Ge_2 . The antiferromagnetic ordering is manifested by the clear jump in the specific heat at $T_{\text{N}} = 4.6$ K as indicated by the arrow. The inset of Fig. 2(a) shows the C_{mag}/T versus T together with the

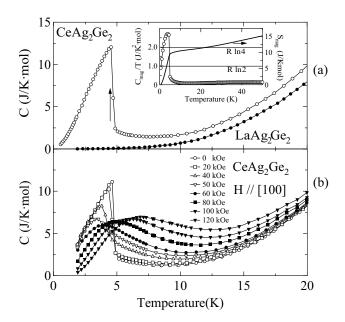


Fig. 2. (a) Temperature dependence of the specific heat of CeAg₂Ge₂ and LaAg₂Ge₂. The inset shows the magnetic entropy. (b) The field dependence of the specific heat of CeAg₂Ge₂ for the field applied along the easy axis of magnetization, namely [100].

magnetic entropy. The entropy reaches $R \ln 4$ not too far away from the magnetic ordering temperature leading to the conclusion that the ground state and the first excited states are closely spaced or nearly degenerate, thus corroborating our CEF analysis of the inverse susceptibility data. Figure 2(b) shows the field dependence of the specific heat for the field applied parallel to the easy axis of magnetization namely [100]. With the increase in the magnetic field the Néel temperature decreases and the antiferromagnetic ordering apparently vanishes at a critical field of 50 kOe indicating a possibility of a field induced quantum critical point in this compound. However, further low temperature measurements are necessary to confirm this.

In summary, we have successfully grown the single crystals of $CeAg_2Ge_2$ by the flux method. $CeAg_2Ge_2$ orders antiferromagnetically at $T_{\rm N}=4.6$ K. The CEF analysis of the inverse susceptibility data indicate the ground state and the first excited states are closely spaced. The heat capacity data support this quasi-quartet ground state. Furthermore, the heat capacity in applied magnetic fields revealed that the Néel temperature vanishes at a critical field of 50 kOe indicating a possible field induced quantum critical point in this compound.

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